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|--|----------|------------------------|
| <br>MICROELETTRICA SCIENTIFICA<br>MILANO ITALY | IM30-AE0 | Doc. N° MO-0064-ING    |
|  |          | Rev. 0<br>Pag. 1 of 19 |

**VARIANTS FOR**  
  
**MICROPROCESSOR OVERCURRENT**  
**AND EARTH FAULT PROTECTION RELAY**  
  
**IM30-AE0**

# OPERATION MANUAL



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|             |                    |             |              |               |              |
|-------------|--------------------|-------------|--------------|---------------|--------------|
|             |                    |             |              |               |              |
| 0           | EMISSION           | 03-1197     | P.Brasca     | D. Abad       |              |
| <b>REV.</b> | <b>DESCRIPTION</b> | <b>DATE</b> | <b>PREP.</b> | <b>CONTR.</b> | <b>APPR.</b> |

## 2.2 ALGORITHM OF THE TIME CURRENT CURVES

The Time Current Curves are generally calculated with the following equation :

$$t(I) = \left[ \frac{(1-B) \cdot (10^a - 1)}{(I/I_s)^a - 1} + B \right] \cdot T_s + t_r \quad \text{where :}$$

$t(I)$  = Actual trip time delay when the input current equals  $I$

$I_s$  = Set minimum pick-up level

$T_s$  = Set time delay :  $t(I) = T_s$  when  $\frac{I}{I_s} = 10$

$t_r$  = Operation time of the output relay on pick-up.

The constants **B** and **a** have different values for the different Time Current Curves.

| Curve Name             | Curve Identifier | B       | a    |
|------------------------|------------------|---------|------|
| IEC A Inverse          | A                | 0       | 0.02 |
| IEC B Very Inverse     | B                | 0       | 1    |
| IEC C Extr. Inverse    | C                | 0       | 2    |
| IEEE Moderate Inverse  | MI               | 0.0226  | 0.02 |
| IEEE Short Inverse     | SI               | 0.00262 | 0.02 |
| IEEE Very Inverse      | VI               | 0.0963  | 2    |
| IEEE Inverse           | I                | 0.18    | 2    |
| IEEE Extremely Inverse | EI               | 0.0352  | 2    |

|   |                   |  |
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## 11. READING OF PROGRAMMED SETTINGS AND SETTING CONFIGURATION

Enter the mode "SET DISP", select the menu "SETTINGS" or "F→RELAY", scroll information available in the menu by keys "+" or "-".

SETTINGS= values of relay's operation parameters as programmed

F→RELAY= output relays associated to the different functions as programmed.

## 12. PROGRAMMING

The relay is supplied with the standard default programming used for factory test. [ Values here below reported ( ---- ) ].

All parameters can be modified as needed in the mode PROG and displayed in the mode SET DISP

**Local Programming by the front face key board is enabled only if no input current is detected (main circuit breakers open). Programming via the serial port is always enabled but a password is required to access the programming mode. The default password is the null string; in the standard application program for communication "MS-COM" it is also provided an emergency password which can be disclosed on request only.**

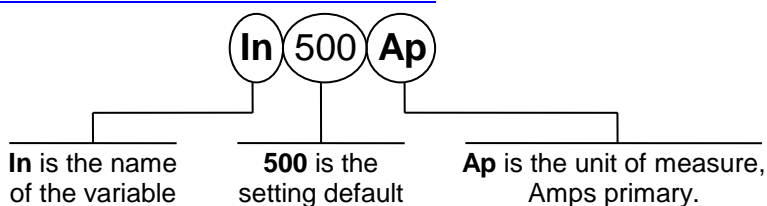
As soon as programming is enabled, the Led PRG/IRF flashes and the reclosing lock-out relay R5 is deenergized..

Enter MODE "PROG" and SELECT either "SETTINGS" for programming of parameters or "F→RELAY" for programming of output relays configuration; enable programming by the indirect operation key PROG.

The key SELECT now scrolls the available parameters. By the key (+) , (-) the displayed values can be modified; to speed up parameter's variation press the key SELECT while "+" or "-" are pressed.

Press key "ENTER/RESET" to validate the set values.

### 12.1 - PROGRAMMING OF FUNCTIONS SETTINGS

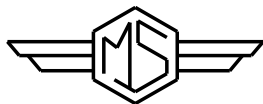


Mode PROG menu SETTINGS. (Production standard settings here under shown).

| Display           | Description  | Setting Range                                 | Step  | Unit |
|-------------------|--|---|---|------|
| <b>Fn 50 Hz</b>   | Mains frequency  | 50 - 60                                       | 10  | Hz   |
| <b>In 500Ap</b>   | Rated primary current of the phase C.Ts.   | 1 - 9999                                      | 1   | A    |
| <b>On 500Ap</b>   | Rated primary current of the C.Ts. or of the tore C.T. supplying the zero sequence current   | 1 - 9999                                      | 1   | A    |
| <b>F(I&gt;) D</b> | Operation characteristic of the low-set overcurrent element:<br>(D) = Independent definite time<br>(A) = IEC Inverse Curve type A<br>(B) = IEC Very Inverse Curve type B<br>(C) = IEC Extremely Inverse Curve type C<br>(MI) = IEEE Moderate Inverse Curve<br>(SI) = IEEE Short Inverse Curve<br>(VI) = IEEE Very Inverse Curve<br>(I) = IEEE Inverse Curve<br>(EI) = IEEE Extremely Inverse Curve | D<br>A<br>B<br>C<br>MI<br>SI<br>VI<br>I<br>EI | D<br>A<br>B<br>C<br>MI<br>SI<br>VI<br>I<br>EI | -    |

| Display                | Description  | Setting Range                                 | Step  | Unit |
|------------------------|--|---|---|------|
| <b>I&gt; .5In</b>      | Trip level of low-set overcurrent element (p.u. of the rated current of the phase C.Ts.)   | 0.5 - 4 - Dis                                 | 0.01  | In   |
| <b>tI&gt; .05s</b>     | Trip time delay of the low-set overcurrent element<br>In the inverse time operation [tI>] is the trip time delay at $I = 10x[I>]$ .  | 0.05 - 30                                     | 0.01  | s    |
| <b>I&gt;&gt; .5In</b>  | Trip level of high-set overcurrent element (p.u. of the rated current of the phase C.Ts.):   | 0.5 - 40 - Dis                                | 0.1   | In   |
| <b>tI&gt;&gt; .05s</b> | Trip time delay of the high-set overcurrent element  | 0.05 - 3                                      | 0.01  | s    |
| <b>F(O&gt;) D</b>      | Operation characteristic of the low-set earth fault element:<br>(D) = Independent definite time<br>(A) = IEC Inverse Curve type A<br>(B) = IEC Very Inverse Curve type B<br>(C) = IEC Extremely Inverse Curve type C<br>(MI) = IEEE Moderate Inverse Curve<br>(SI) = IEEE Short Inverse Curve<br>(VI) = IEEE Very Inverse Curve<br>(I) = IEEE Inverse Curve<br>(EI) = IEEE Extremely Inverse Curve | D<br>A<br>B<br>C<br>MI<br>SI<br>VI<br>I<br>EI | D<br>A<br>B<br>C<br>MI<br>SI<br>VI<br>I<br>EI | -    |
| <b>O&gt; .02On</b>     | Trip level of low-set earth fault element (p.u. of the rated current of the C.Ts. for zero sequence detection)   | 0.02 - 0.4 - Dis                              | 0.01  | On   |
| <b>tO&gt; .05s</b>     | Trip time delay of low-set earth fault element. In the inverse time operation [tO>] is the trip time delay at $I = 10x[O>]$ .  | 0.05 - 30                                     | 0.01  | s    |
| <b>O&gt;&gt; .02On</b> | Trip level of high-set earth fault element (p.u. of the rated current of the C.Ts. for zero sequence detection)  | 0.02 - 4 - Dis                                | 0.01  | On   |
| <b>tO&gt;&gt; .05s</b> | Trip time delay of the high-set earth fault element  | 0.05 - 3                                      | 0.01  | s    |
| <b>tBO .05s</b>        | Max. reset time delay of the instantaneous elements after tripping of the time delayed elements and time delay for activation of the output relay associated to the Breaker Failure function   | 0.05 - 0.25                                   | 0.01  | s    |
| <b>2I&gt;&gt; OFF</b>  | Automatic doubling of high set overcurrent level When set to ON the level I>> is automatically doubled (from I>> to 2I>>) Within the first 60ms from switch-on, the inrush current gets higher than 1,5 In. As soon as the current drops below 1,25 In the level I>> comes back to its normal set value (from 2I>> to I>>).  | ON - OFF                                      | ON - OFF                                      | -    |
| <b>NodAd 1</b>         | Identification number for connection on serial communication bus   | 1 - 250                                       | 1   | -    |

**The setting Dis indicates that the function is disactivated.**



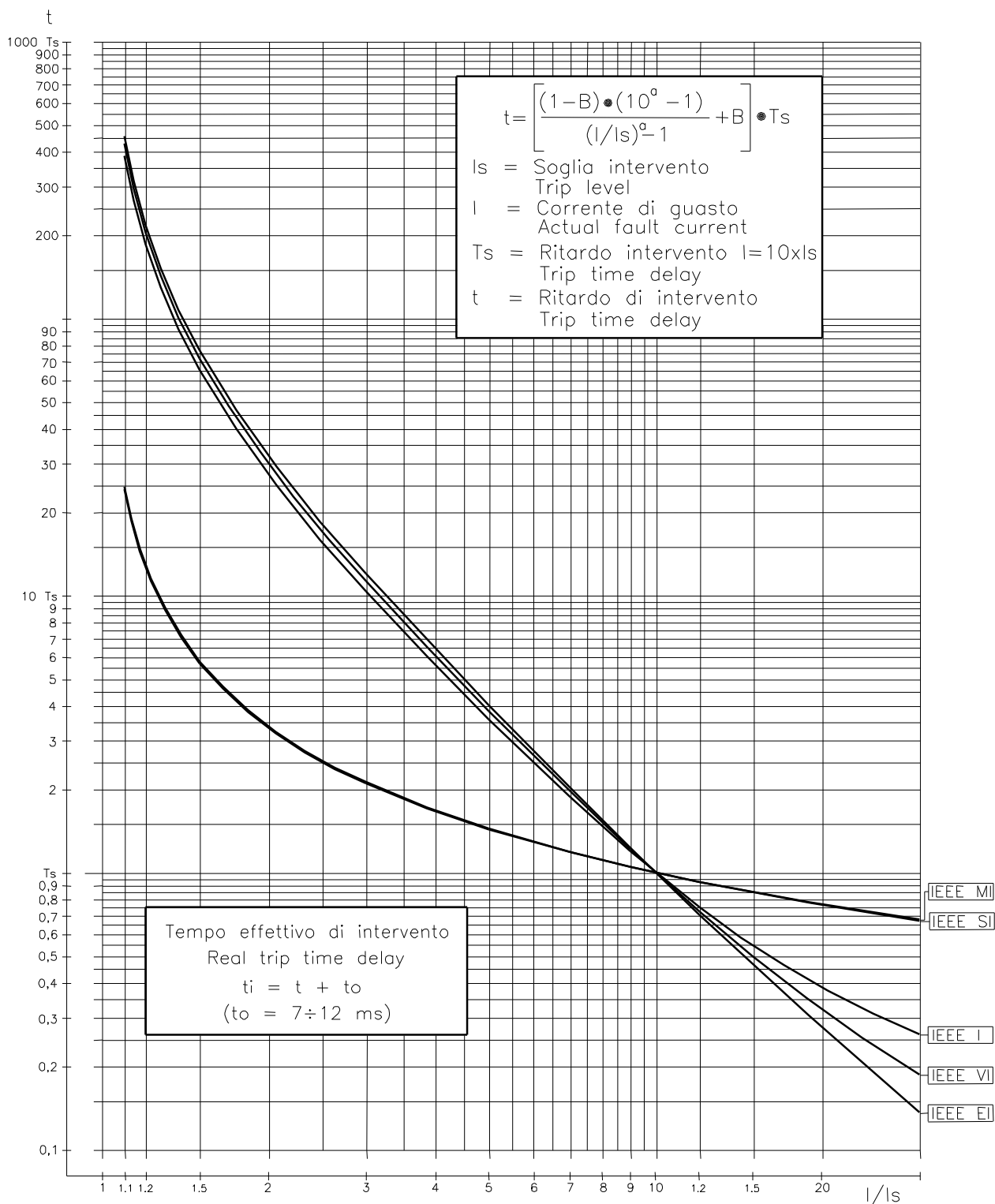
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### 20. TIME CURRENT CURVES IEEE (TU0354 Rev.0 2/2)



| Curve Type             | B       | a    |
|------------------------|---------|------|
| MI=IEEE Moderate Inv.  | 0.0226  | 0.02 |
| SI=IEEE Short Inv.     | 0.00262 | 0.02 |
| VI=IEEE Very Inv.      | 0.0963  | 2    |
| I=IEEE Inverse         | 0.18    | 2    |
| EI=IEEE Extremely Inv. | 0.0352  | 2    |

$$F51 \begin{cases} I_s = I > = (0.5-4)I_n \\ T_s = tI > = (0.05-30)s \end{cases}$$

$$F51N \begin{cases} I_s = 0 > = (0.02-0.4)0_n \\ T_s = t0 > = (0.05-30)s \end{cases}$$